

**SCD12H THRU SCD110H**

● **FEATURES**

- \* Halogen-free type
- \* Compliance to RoHS product
- \* Lead less chip form, no lead damage
- \* Low power loss, High efficiency
- \* High current capability, low VF
- \* Plastic package has Underwriters Laboratory Flammability Classification 94V-0

● **APPLICATION**

- \* Switching mode power supply applications
- \* Portable equipment battery applications
- \* High frequency rectification
- \* DC / DC Converter
- \* Telecommunication

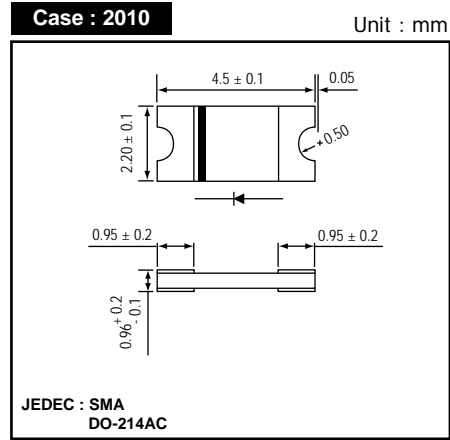
● **MECHANICAL DATA**

**Case :** Packed with FRP substrate and epoxy underfilled  
**Terminals :** Pure Tin plated (Lead-Free), solderable per MIL-STD-750, Method 2026.  
**Polarity :** Laser Cathode band marking  
**Weight :** 0.02 gram

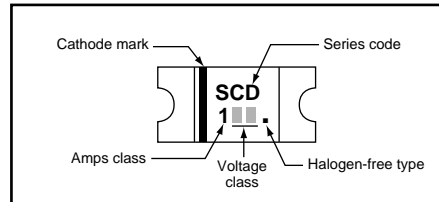
● **PACKING**

- \* 3,000 pieces per 7" (178mm ± 2mm) reel
- \* 4 reels per box
- \* 6 boxes per carton

● **OUTLINE DIMENSIONS**



● **MARKING**



**Absolute Maximum Ratings (Ta = 25 °C)**

ITEM	Symbol	Conditions	Rating				Unit
			SCD12H	SCD14H	SCD16H	SCD110H	
Repetitive peak reverse voltage	VRRM		20	40	60	100	V
Average forward current	IF(AV)		1.0				A
Peak forward surge current	IFSM	8.3ms single half sine-wave	30				A
Operating junction temperature Range	Tj		-55 to +125		-55 to +150		°C
Storage temperature Range	TSTG		-55 to +150				°C

**Electrical characteristics (Ta = 25 °C)**

ITEM	Symbol	Conditions	Type	Min.	Typ.	Max.	Unit
Forward voltage (NOTE 1)	VF	IF = 0.1A	SCD12H	-	0.34	-	V
		IF = 0.5A	/	-	0.41	-	
		IF = 1.0A	SCD14H	-	0.47	0.50	
		IF = 0.1A	SCD16H	-	0.38	-	V
IF = 0.5A		-	0.48	-			
IF = 1.0A		-	0.60	0.70			
		IF = 0.1A	SCD110H	-	0.45	-	V
		IF = 0.5A		-	0.63	-	
		IF = 1.0A		-	0.76	0.85	
Repetitive peak reverse current	IRRM	VR = Max. VRRM , Ta = 25 °C		-	0.02	0.20	mA
Junction capacitance	Cj	VR = 4V, f = 1.0 MHz		-	110	-	pF
Thermal resistance	Rth(JA)	Junction to ambient (NOTE 2)		-	88	-	°C/W
	Rth(JL)	Junction to lead (NOTE 2)		-	28	-	°C/W

NOTES : (1) Pulse test width PW=300usec , 1% duty cycle.  
 (2) Mounted on P.C. board with 0.2 x 0.2"(5.0 x5.0mm) copper pad areas.

FIG.1 - FORWARD CURRENT DERATING CURVE

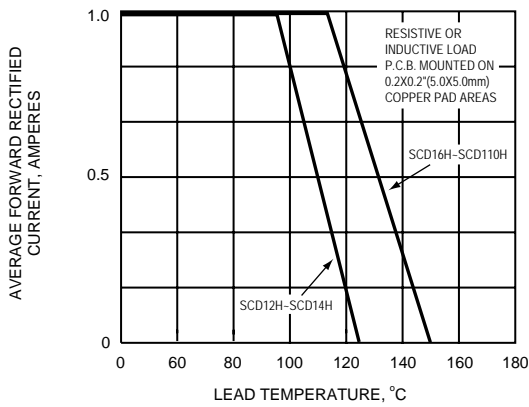


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

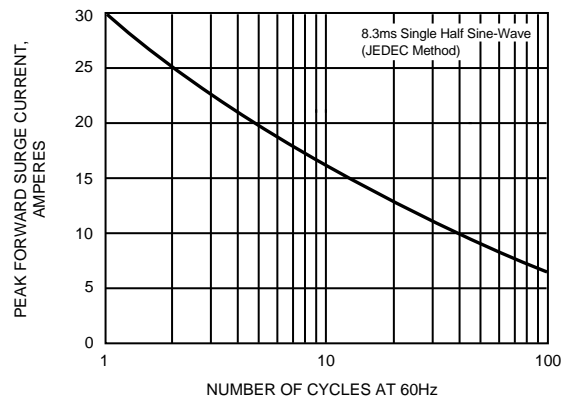


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

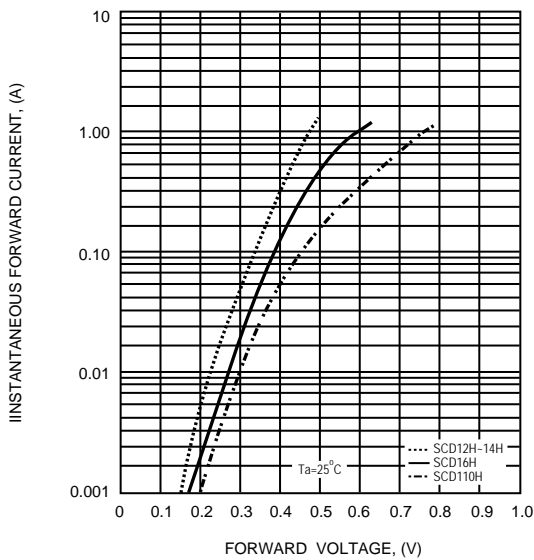


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

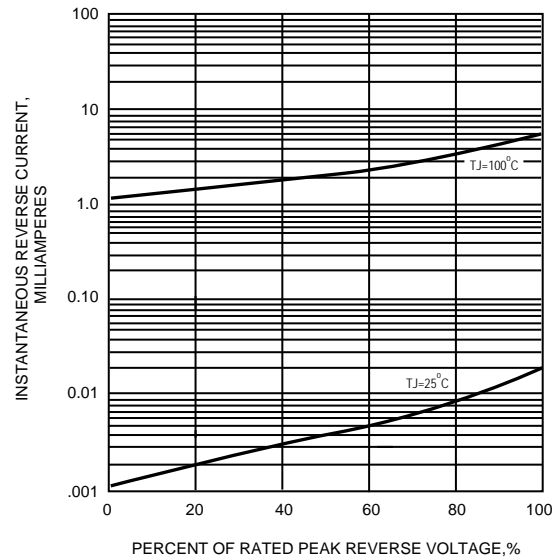


FIG.5 - TYPICAL JUNCTION CAPACITANCE

